## NSN 5962-01-379-4682

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Maximum Power Dissipation Rating:
303.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Wgu-2c/b guid e/i fscm 96214
Features Provided:
Bipolar and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Programmable array logic, altered
Voltage Rating And Type Per Characteristic:
-1.5 volts absolute input and 5.5 volts absolute input
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883
standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Specification Data:
67268-5962-8851501ra government standard
Departure From Cited Designator:
Programmed per (30003) 704as11589-102 or (01295) 1711589-102
Shelf Life:
N/a

Vec - demil/mli

**Unit Of Measure:** 

Demilitarization:

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